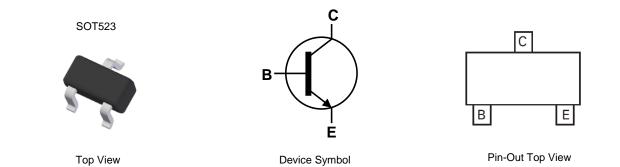


#### Features

- BV<sub>CEO</sub> > 40V
- I<sub>C</sub> = 200mA Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary PNP Type: MMBT3906T
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: SOT523
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.002 grams (Approximate)



### Ordering Information (Note 4)

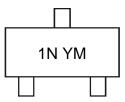
Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
MMBT3904T-7-F	Active	AEC-Q101	1N	7	8	3,000
MMBT3904T-13-F	Active	AEC-Q101	1N	13	8	10,000

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



 $\begin{array}{l} 1 N = \mbox{Product Type Marking Code} \\ YM = \mbox{Date Code Marking} \\ Y \mbox{ or } \overline{Y} = \mbox{Year (ex: A = 2013)} \\ M \mbox{ or } \overline{M} = \mbox{Month (ex: 9 = September)} \end{array}$ 

Notes:

Year	201	3	2014	2015	2016	2017	2018	2019	9 20	20	2021	2022	2023
Code	Α		В	С	D	E	F	G	ŀ	1	I	J	K
Monti	h	Ja	n Feb	o Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	•	1	2	3	4	5	6	7	8	9	0	N	D



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	40	V
Emitter-Base Voltage	V <sub>EBO</sub>	6	V
Collector Current	Ιc	200	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

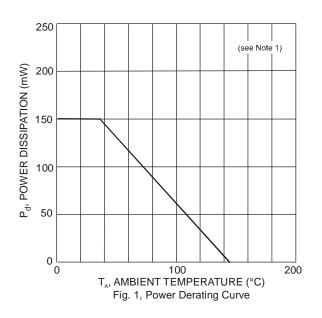
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	150	mW
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	833	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

# ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state. 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

# **Thermal Characteristics and Derating Information**



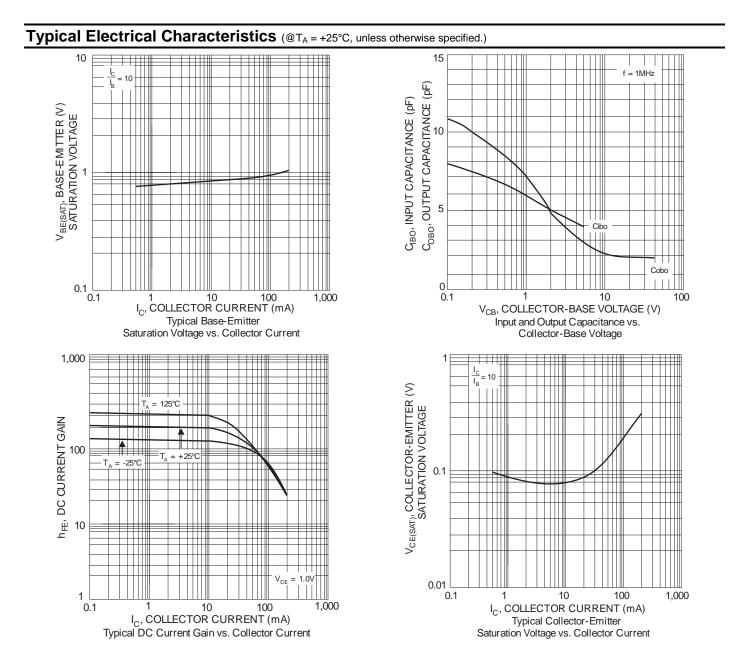


# Electrical Characteristics (@T<sub>A</sub> = +25°C unless otherwise specified.)

Characteristic	Cumphical	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	Symbol	Min	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	60		V	$I_{\rm C} = 10 \mu {\rm A}, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	BV <sub>CBO</sub> BV <sub>CEO</sub>	40		V	$I_{\rm C} = 10\mu A, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage		40 6		V	
Collector Cutoff Current	BV <sub>EBO</sub>		50	-	$I_E = 10\mu A, I_C = 0$
Base Cutoff Current	ICEX		50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3V$
	IBL		50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3V$
ON CHARACTERISTICS (Note 7)				1	1 100-1 1/ 1/
		40	—		$I_{C} = 100\mu A, V_{CE} = 1V$
DC Current Gain		70	200		$I_{C} = 1mA, V_{CE} = 1V$
DC Current Gain	h <sub>FE</sub>	100 60	300	_	$I_C = 10mA, V_{CE} = 1V$
		30			$I_{C} = 50 \text{mA}, V_{CE} = 1 \text{V}$
		00			$I_{C} = 100 \text{mA}, V_{CE} = 1 \text{V}$
Collector-Emitter Saturation Voltage	V <sub>CE</sub> (SAT)	_	0.20	V	$I_{C} = 10 \text{mA}, I_{B} = 1 \text{mA}$
<b>v</b>	02(0/11)		0.30		$I_{\rm C} = 50 {\rm mA}, I_{\rm B} = 5 {\rm mA}$
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	0.65	0.85	V	$I_C = 10mA$ , $I_B = 1mA$
<b>b</b>			0.95		$I_{\rm C} = 50$ mA, $I_{\rm B} = 5$ mA
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	Сово		4	pF	$V_{CB} = 5V, f = 1.0MHz, I_E = 0$
Input Capacitance	CIBO		8	pF	$V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$
Input Impedance	hie	1	10	kΩ	
Voltage Feedback Ratio	h <sub>RE</sub>	0.5	8.0	x 10 <sup>-4</sup>	$V_{CE} = 10V, I_C = 1mA,$
Small Signal Current Gain	h <sub>FE</sub>	100	400	—	f = 1.0MHz
Output Admittance	h <sub>OE</sub>	1	40	μS	
Current Gain-Bandwidth Product	fт	300		MHz	$V_{CE} = 20V, I_C = 10mA,$ f = 100MHz
Noise Figure	NF		5	dB	$V_{CC} = 5V, I_C = 100\mu A,$
6			5	uВ	$R_S = 1k\Omega$ , $f = 1MHz$
SWITCHING CHARACTERISTICS					
Delay Time	t <sub>D</sub>	_	35	ns	$V_{CC} = 3V, I_C = 10mA,$
Rise Time	t <sub>R</sub>	_	35	ns	$V_{BE(OFF)}$ = -0.5V, $I_{B1}$ = 1mA
Storage Time	ts		200	ns	$V_{CC} = 3.0V, I_{C} = 10mA$
Fall Time	t <sub>F</sub>		50	ns	I <sub>B1</sub> =- I <sub>B2</sub> = 1.0mA

Note: 7. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.

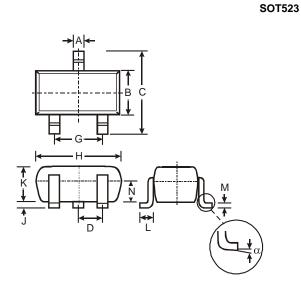






# **Package Outline Dimensions**

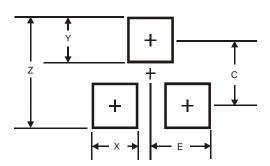
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT523						
Dim	Min	Max	Тур			
Α	0.15	0.30	0.22			
В	0.75	0.85	0.80			
C	1.45	1.75	1.60			
D	_		0.50			
G	0.90	1.10	1.00			
н	1.50	1.70	1.60			
J	0.00	0.10	0.05			
Κ	0.60	0.80	0.75			
L	0.10	0.30	0.22			
Μ	0.10	0.20	0.12			
Ν	0.45	0.65	0.50			
α	0°	8°				
All	Dimens	ions in	mm			

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
Z	1.8
Х	0.4
Y	0.51
С	1.3
E	0.7

SOT523



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